PDTA143X/123J/143Z/114Y/124XQC-Q series

50 V, 100 mA PNP resistor-equipped transistors

Rev. 1 — 30 September 2021 Product data sheet

1. General description

100 mA PNP Resistor-Equipped Transistor (RET) family in an ultra small DFN1412D-3 (SOT8009) leadless Surface-Mounted Device (SMD) plastic package with side-wettable flanks.

Table 1. Product overview

Type number	R1	R2	Package		NPN complement:
	kΩ	kΩ	Nexperia	JEDEC	
PDTA143XQC-Q	4.7	10	SOT8009	MO-340CA	PDTC143XQC-Q
PDTA123JQC-Q	2.2	47			PDTC123JQC-Q
PDTA143ZQC-Q	4.7	47			PDTC143ZQC-Q
PDTA114YQC-Q	10	47			PDTC114YQC-Q
PDTA124XQC-Q	22	47			PDTC124XQC-Q

2. Features and benefits

- 100 mA output current capability
- Built-in resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- Low package height of 0.5 mm
- Suitable for Automatic Optical Inspection (AOI) of solder joint
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Digital applications
- Cost saving alternative for BC857-Q series in digital applications
- Controlling IC inputs
- Switching loads

4. Quick reference data

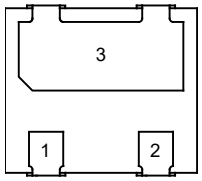
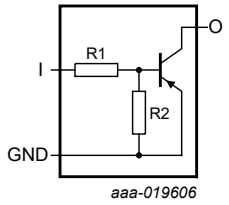
Table 2. Quick reference data

T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-50	V
I_O	output current		-	-	-100	mA

5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)	 Transparent top view	 aaa-019606
2	GND	GND (emitter)		
3	O	output (collector)		

6. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
PDTA143XQC-Q	DFN1412D-3	plastic leadless ultra small outline package with side-wettable flanks (SWF); 3 terminals; 0.8 mm pitch; body: 1.4 x 1.2 x 0.48 mm	SOT8009
PDTA123JQC-Q			
PDTA143ZQC-Q			
PDTA114YQC-Q			
PDTA124XQC-Q			

7. Marking

Table 5. Marking

Type number	Marking code
PDTA143XQC-Q	8F
PDTA123JQC-Q	8C
PDTA143ZQC-Q	8G
PDTA114YQC-Q	8B
PDTA124XQC-Q	6F

8. Limiting values

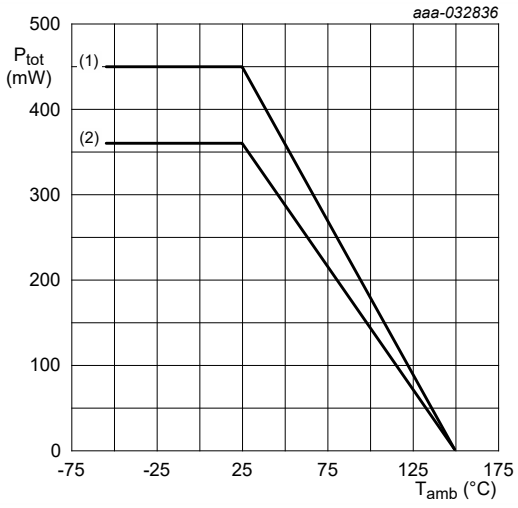
Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	-50	V
V_{CEO}	collector-emitter voltage	open base		-	-50	V
V_{EBO}	emitter-base voltage					
	PDTA143XQC-Q	open collector		-	-7	V
	PDTA123JQC-Q			-	-5	V
	PDTA143ZQC-Q			-	-5	V
	PDTA114YQC-Q			-	-6	V
	PDTA124XQC-Q			-	-7	V
V_I	input voltage					
	PDTA143XQC-Q			-30	+7	V
	PDTA123JQC-Q			-12	+5	V
	PDTA143ZQC-Q			-30	+5	V
	PDTA114YQC-Q			-40	+6	V
	PDTA124XQC-Q			-40	+7	V
I_O	output current			-	-100	mA
P_{tot}	total power dissipation	T_{amb} ≤ 25 °C	[1]	-	360	mW
			[2]	-	450	mW
T_j	junction temperature			-	150	°C
T_{amb}	ambient temperature			-55	150	°C
T_{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided; 35 µm copper; tin-plated and standard footprint.
[2] Device mounted on an FR4 PCB; single-sided; 70 µm copper; tin-plated and standard footprint.



(1) FR4 PCB; single-sided; 70 µm copper; standard footprint
(2) FR4 PCB; single-sided; 35 µm copper; standard footprint

Fig. 1. Power derating curves

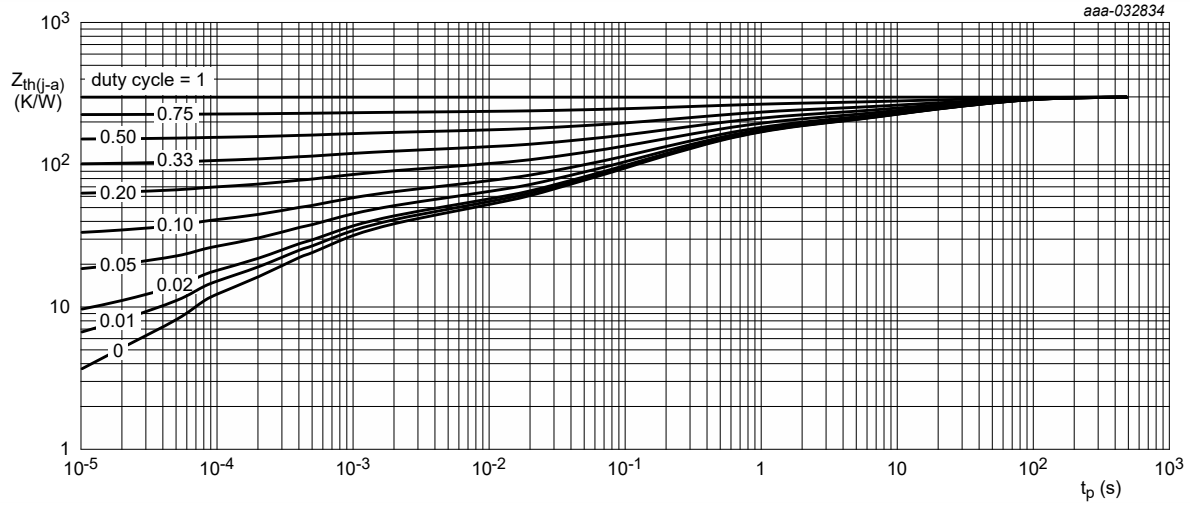
9. Thermal characteristics

Table 7. Thermal characteristics

T_{amb} = 25 °C unless otherwise specified.

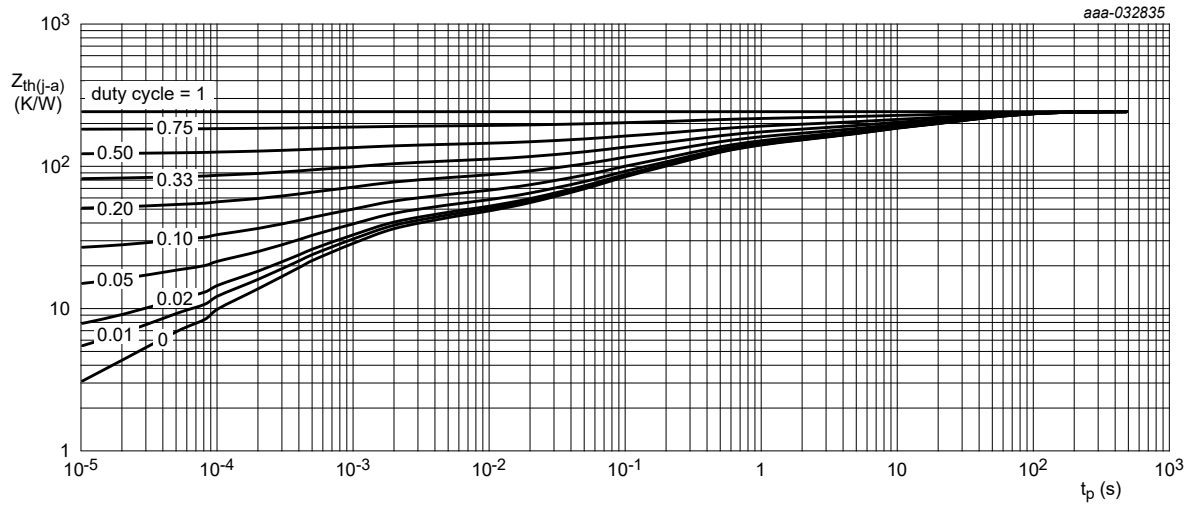
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	348	K/W
			[2]	-	-	278	K/W

[1] Device mounted on an FR4 PCB; single-sided; 35 µm copper; tin-plated and standard footprint.
[2] Device mounted on an FR4 PCB; single-sided; 70 µm copper; tin-plated and standard footprint.



FR4 PCB; single-sided; 35 µm copper; tin-plated and standard footprint.

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; single-sided; 70 µm copper; tin-plated and standard footprint.

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

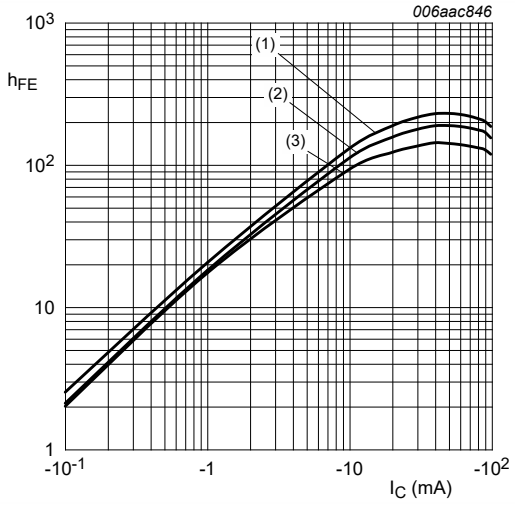
Table 8. Characteristics

T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	I_C = -100 µA; I_E = 0 A		-50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	I_C = -2 mA; I_B = 0 A		-50	-	-	V
I_{CBO}	collector-base cut-off current	V_{CB} = -50 V; I_E = 0 A		-	-	-100	nA
I_{CEO}	collector-emitter cut-off current	V_{CE} = -30 V; I_B = 0 A		-	-	-100	nA
		V_{CE} = -30 V; I_B = 0 A; T_j = 150 °C		-	-	-5	µA
I_{EBO}	emitter-base cut-off current						
	PDTA143XQC-Q	V_{EB} = -5 V; I_C = 0 A		-	-	-600	µA
	PDTA123JQC-Q			-	-	-180	µA
	PDTA143ZQC-Q			-	-	-170	µA
	PDTA114YQC-Q					-150	µA
	PDTA124XQC-Q					-120	µA
h_{FE}	DC current gain						
	PDTA143XQC-Q	V_{CE} = -5 V; I_C = -10 mA		50	-	-	
	PDTA123JQC-Q			100	-	-	
	PDTA143ZQC-Q			100	-	-	
	PDTA114YQC-Q	V_{CE} = -5 V; I_C = -5 mA		100	-	-	
	PDTA124XQC-Q			80	-	-	
V_{CEsat}	collector-emitter saturation voltage						
	PDTA143XQC-Q	I_C = -10 mA; I_B = -0.5 mA		-	-	-100	mV
	PDTA123JQC-Q	I_C = -5 mA; I_B = -0.25 mA		-	-	-100	mV
	PDTA143ZQC-Q			-	-	-100	mV
	PDTA114YQC-Q			-	-	-100	mV
	PDTA124XQC-Q	I_C = -10 mA; I_B = -0.5 mA		-	-	-100	mV
$V_{I(off)}$	off-state input voltage						
	PDTA143XQC-Q	V_{CE} = -5 V ; I_C = -100 µA		-	-0.9	-0.3	V
	PDTA123JQC-Q			-	-0.6	-0.5	V
	PDTA143ZQC-Q			-	-0.6	-0.5	V
	PDTA114YQC-Q			-	-0.7	-0.5	V
	PDTA124XQC-Q			-	-0.8	-0.5	V
$V_{I(on)}$	on-state input voltage						
	PDTA143XQC-Q	V_{CE} = -0.3 V ; I_C = -20 mA		-2.5	-1.5	-	V
	PDTA123JQC-Q	V_{CE} = -0.3 V ; I_C = -5 mA		-1.1	-0.75	-	V
	PDTA143ZQC-Q	V_{CE} = -0.3 V ; I_C = -5 mA		-1.3	-0.9	-	V
	PDTA114YQC-Q	V_{CE} = -0.3 V ; I_C = -1 mA		-1.4	-0.8	-	V
	PDTA124XQC-Q	V_{CE} = -0.3 V ; I_C = -2 mA		-2	-1.1	-	V

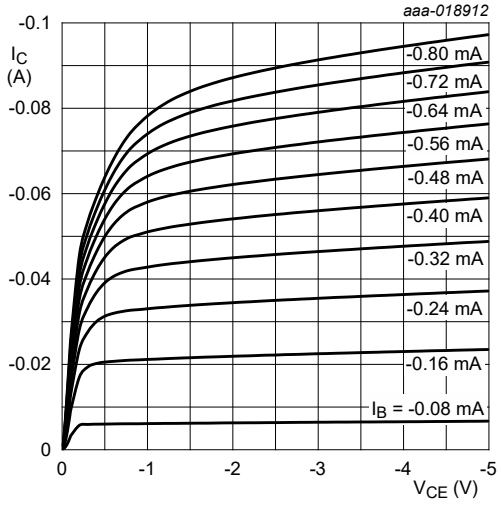
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
R1	bias resistor 1 (input)						
	PDTA143XQC-Q		[1]	3.3	4.7	6.1	kΩ
	PDTA123JQC-Q			1.54	2.2	2.86	kΩ
	PDTA143ZQC-Q			3.3	4.7	6.1	kΩ
	PDTA114YQC-Q			7	10	13	kΩ
	PDTA124XQC-Q			15.4	22	28.6	kΩ
R2/R1	bias resistor ratio						
	PDTA143XQC-Q		[1]	1.7	2.13	2.6	
	PDTA123JQC-Q			17	21	26	
	PDTA143ZQC-Q			8	10	12	
	PDTA114YQC-Q			3.7	4.7	5.7	
	PDTA124XQC-Q			1.7	2.13	2.6	
f_T	transition frequency	V_{CE} = -5 V; I_C = -10 mA; f = 100 MHz	[2]	-	180	-	MHz
C_c	collector capacitance	V_{CB} = -10 V; I_E = i_e = 0 A; f = 1 MHz		-	-	3	pF

[1] See "Section 11: Test information" for resistor calculation and test conditions
[2] Characteristics of built-in transistor



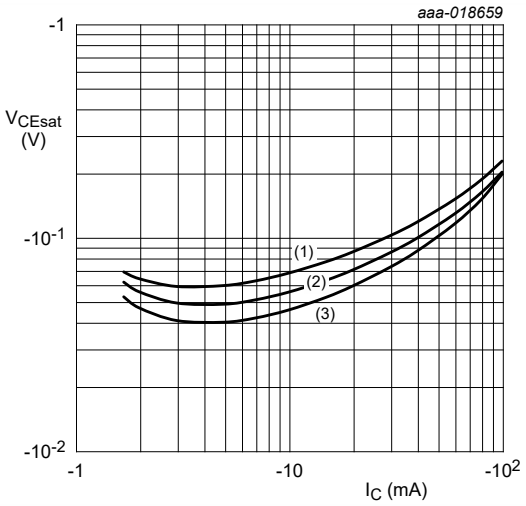
V_{CE} = -5 V
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 4. PDTA143XQC-Q: DC current gain as a function of collector current; typical values



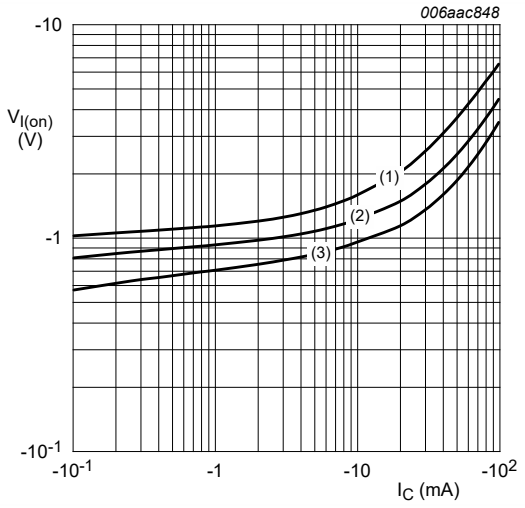
T_{amb} = 25 °C

Fig. 5. PDTA143XQC-Q: Collector current as a function of collector-emitter voltage; typical values



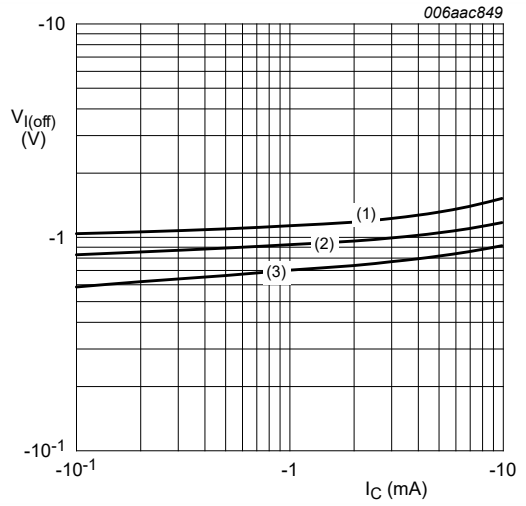
I_C/I_B = 20
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 6. PDTA143XQC-Q: Collector-emitter saturation voltage as a function of collector current; typical values



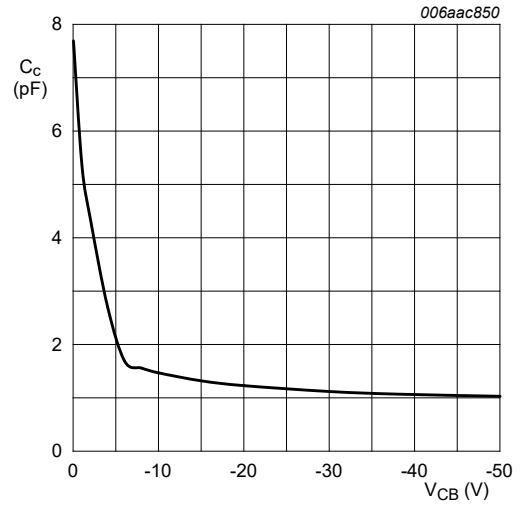
V_{CE} = -0.3 V
(1) T_{amb} = -40 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 100 °C

Fig. 7. PDTA143XQC-Q: On-state input voltage as a function of collector current; typical values



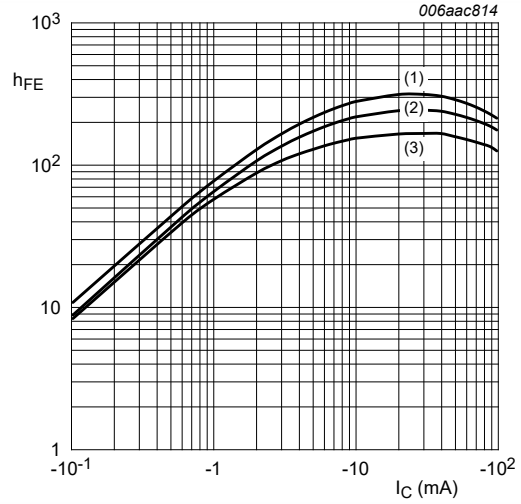
V_{CE} = -5 V
(1) T_{amb} = -40 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 100 °C

Fig. 8. PDTA143XQC-Q: Off-state input voltage as a function of collector current; typical values



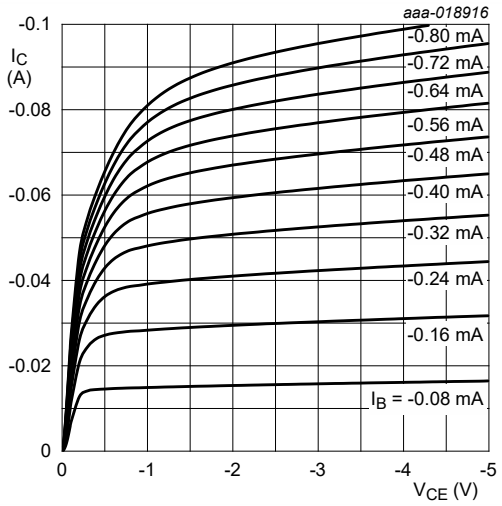
f = 1 MHz
T_{amb} = 25 °C

Fig. 9. PDTA143XQC-Q: Collector capacitance as a function of collector-base voltage; typical values



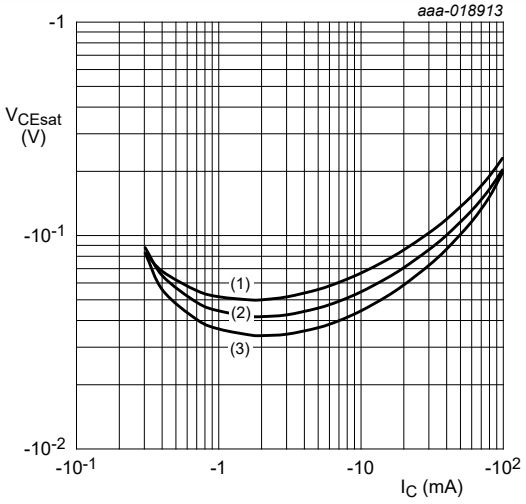
V_{CE} = -5 V
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 10. PDTA123JQC-Q: DC current gain as a function of collector current; typical values



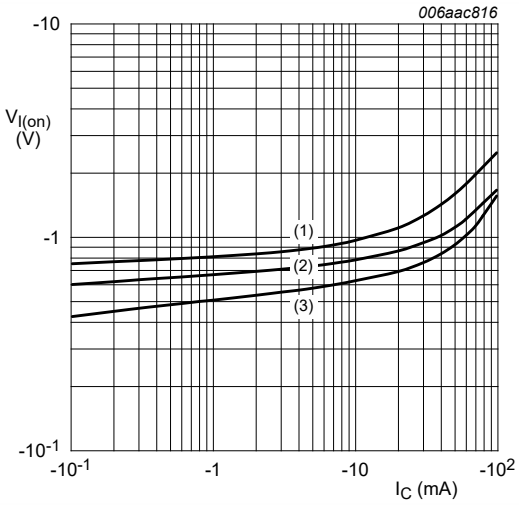
T_{amb} = 25 °C

Fig. 11. PDTA123JQC-Q: Collector current as a function of collector-emitter voltage; typical values



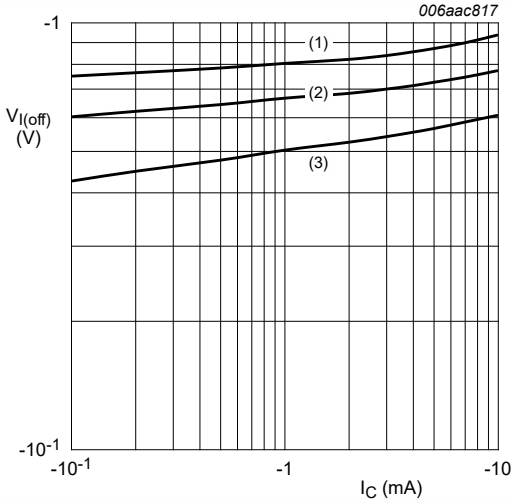
I_C/I_B = 20
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 12. PDTA123JQC-Q: Collector-emitter saturation voltage as a function of collector current; typical values



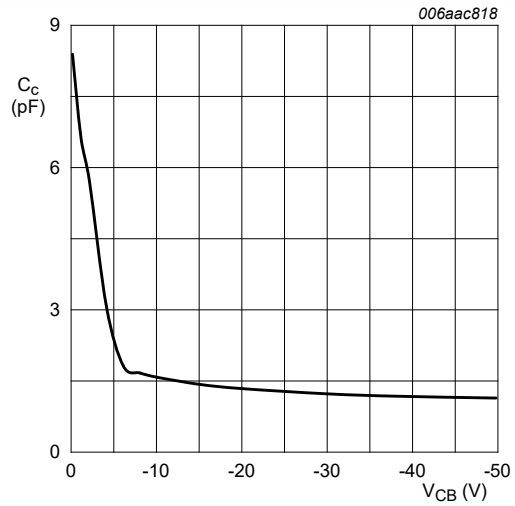
V_{CE} = -0.3 V
(1) T_{amb} = -40 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 100 °C

Fig. 13. PDTA123JQC-Q: On-state input voltage as a function of collector current; typical values



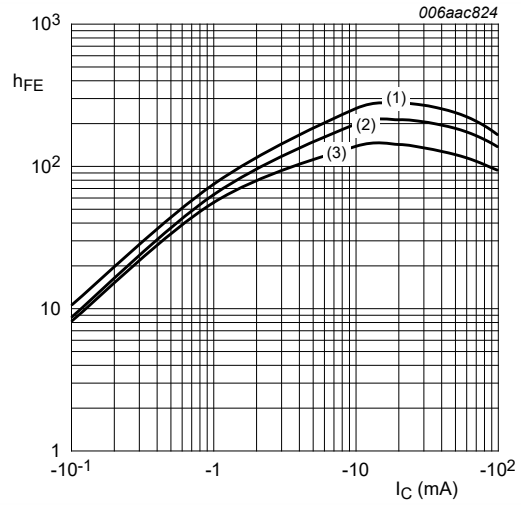
V_{CE} = -5 V
(1) T_{amb} = -40 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 100 °C

Fig. 14. PDTA123JQC-Q: Off-state input voltage as a function of collector current; typical values



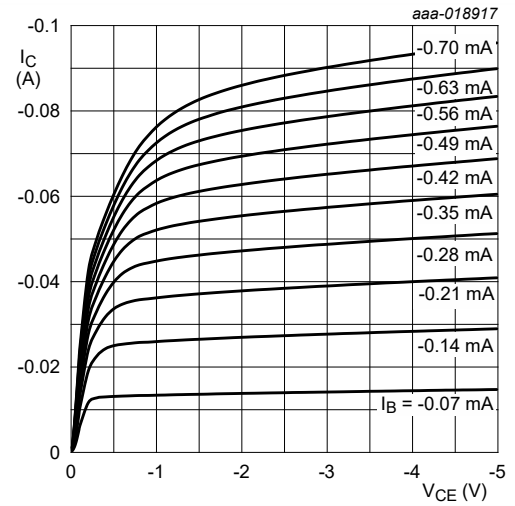
f = 1 MHz
T_{amb} = 25 °C

Fig. 15. PDTA123JQC-Q: Collector capacitance as a function of collector-base voltage; typical values



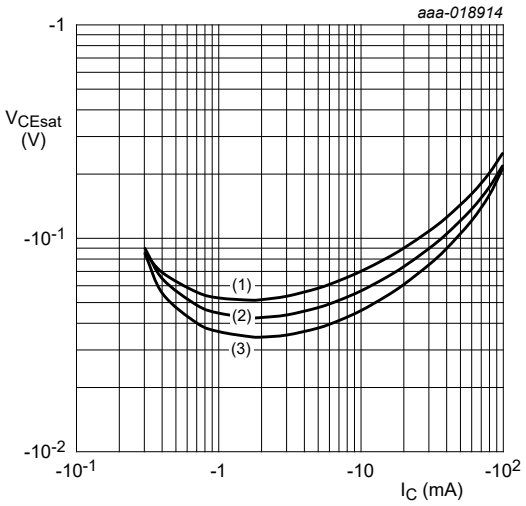
V_{CE} = -5 V
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 16. PDTA143ZQC-Q: DC current gain as a function of collector current; typical values



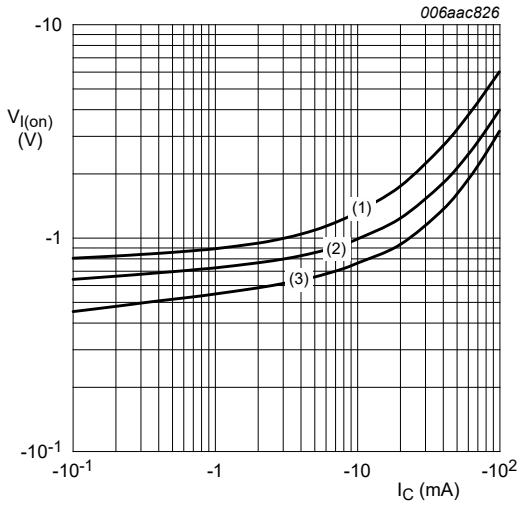
T_{amb} = 25 °C

Fig. 17. PDTA143ZQC-Q: Collector current as a function of collector-emitter voltage; typical values



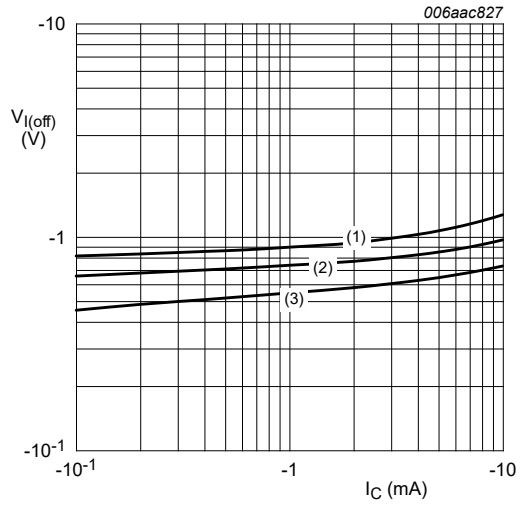
I_C/I_B = 20
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 18. PDTA143ZQC-Q: Collector-emitter saturation voltage as a function of collector current; typical values



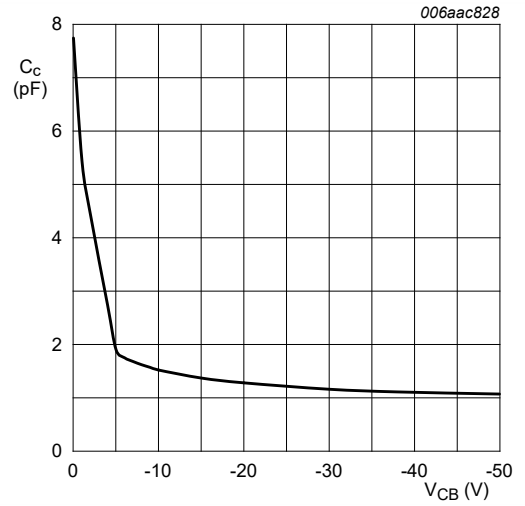
V_{CE} = -0.3 V
(1) T_{amb} = -40 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 100 °C

Fig. 19. PDTA143ZQC-Q: On-state input voltage as a function of collector current; typical values



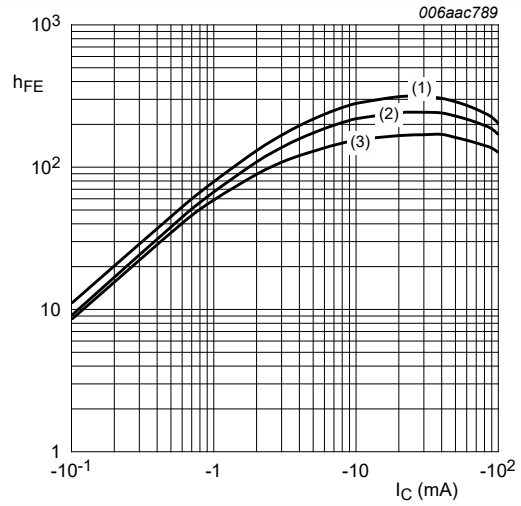
V_{CE} = -5 V
(1) T_{amb} = -40 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 100 °C

Fig. 20. PDTA143ZQC-Q: Off-state input voltage as a function of collector current; typical values



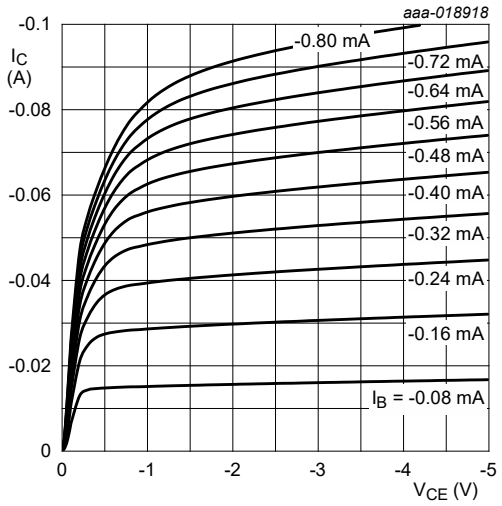
f = 1 MHz
T_{amb} = 25 °C

Fig. 21. PDTA143ZQC-Q: Collector capacitance as a function of collector-base voltage; typical values



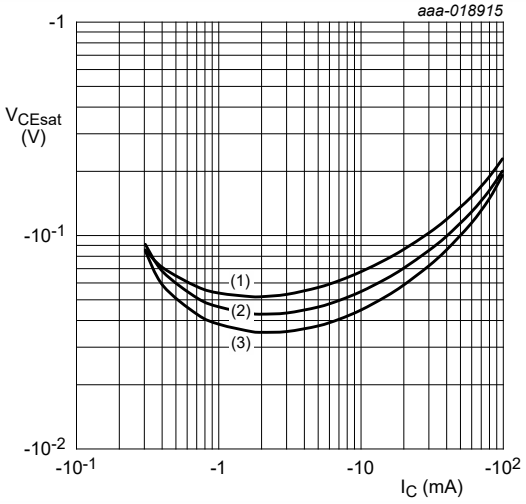
V_{CE} = -5 V
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 22. PDTA114YQC-Q: DC current gain as a function of collector current; typical values



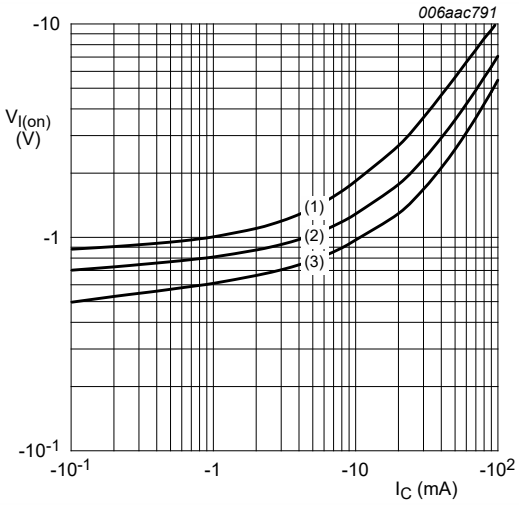
T_{amb} = 25 °C

Fig. 23. PDTA114YQC-Q: Collector current as a function of collector-emitter voltage; typical values



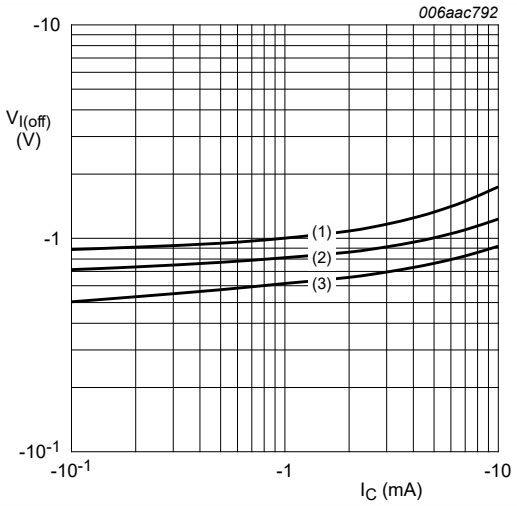
I_C/I_B = 20
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 24. PDTA114YQC-Q: Collector-emitter saturation voltage as a function of collector current; typical values



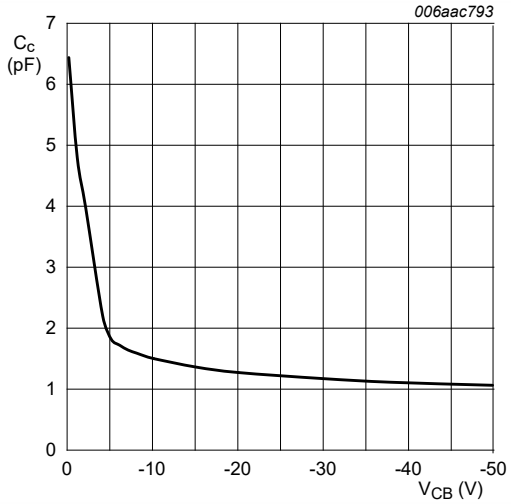
V_{CE} = -0.3 V
(1) T_{amb} = -40 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 100 °C

Fig. 25. PDTA114YQC-Q: On-state input voltage as a function of collector current; typical values



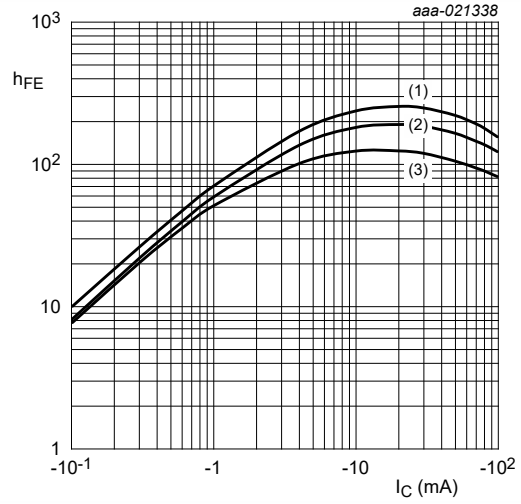
V_{CE} = -5 V
(1) T_{amb} = -40 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 100 °C

Fig. 26. PDTA114YQC-Q: Off-state input voltage as a function of collector current; typical values



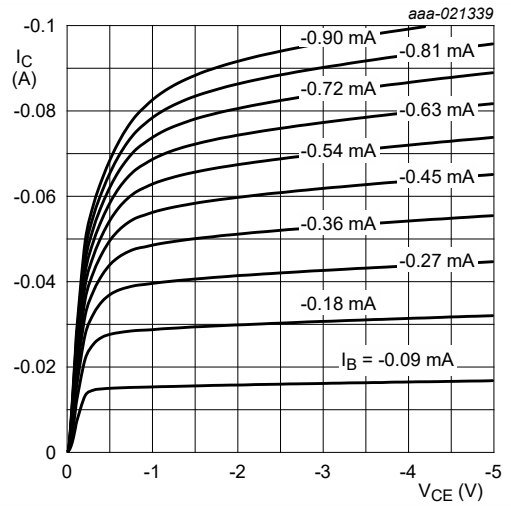
f = 1 MHz
T_{amb} = 25 °C

Fig. 27. PDTA114YQC-Q: Collector capacitance as a function of collector-base voltage; typical values



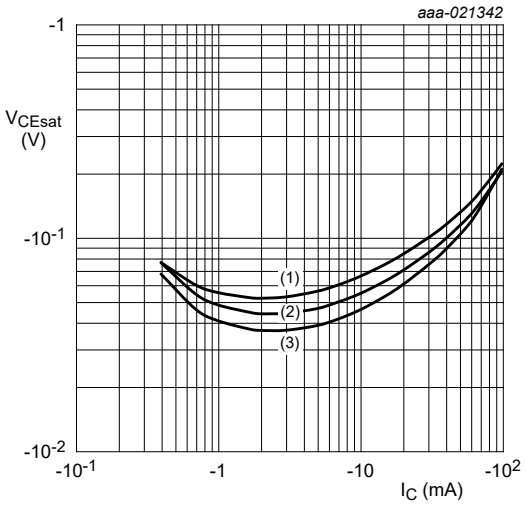
V_{CE} = -5 V
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 28. PDTA124XQC-Q: DC current gain as a function of collector current; typical values



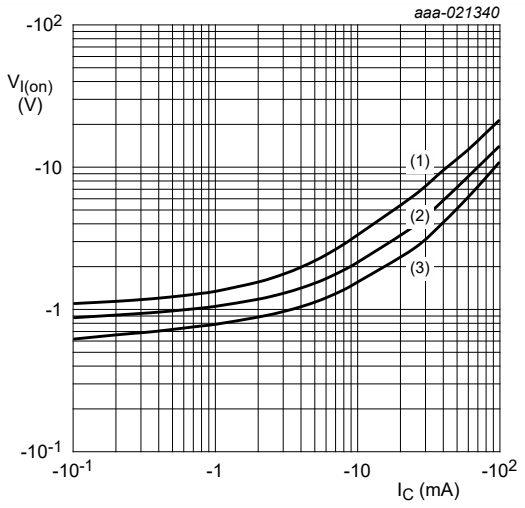
T_{amb} = 25 °C

Fig. 29. PDTA124XQC-Q: Collector current as a function of collector-emitter voltage; typical values



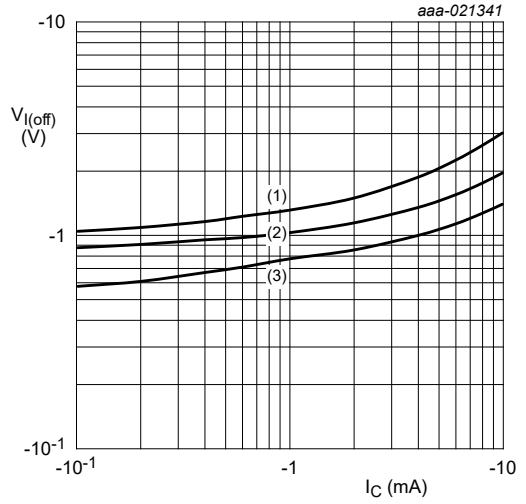
I_C/I_B = 10
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 30. PDTA124XQC-Q: Collector-emitter saturation voltage as a function of collector current; typical values



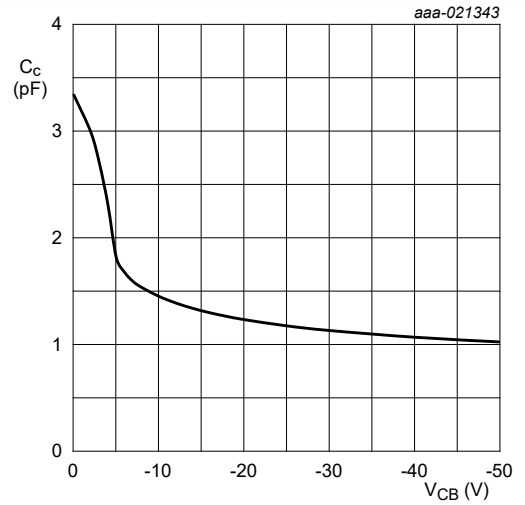
V_{CE} = -0.3 V
(1) T_{amb} = -40 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 100 °C

Fig. 31. PDTA124XQC-Q: On-state input voltage as a function of collector current; typical values



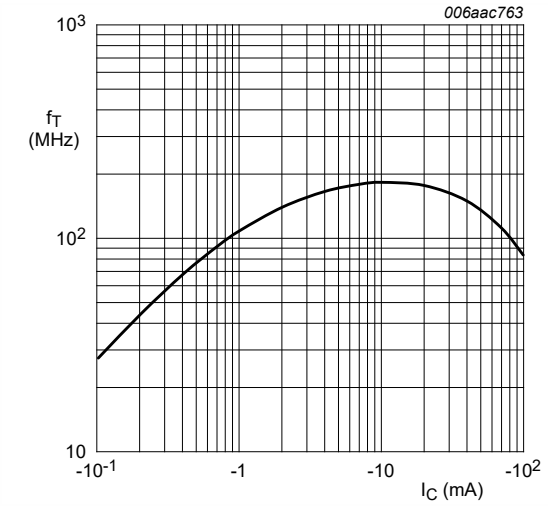
V_{CE} = -5 V
(1) T_{amb} = -40 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 100 °C

Fig. 32. PDTA124XQC-Q: Off-state input voltage as a function of collector current; typical values



f = 1 MHz
T_{amb} = 25 °C

Fig. 33. PDTA124XQC-Q: Collector capacitance as a function of collector-base voltage; typical values



f = 100 MHz
T_{amb} = 25 °C
V_{CE} = -5 V

Fig. 34. Transition frequency as a function of collector current; typical values of built-in transistor

11. Test information

Resistor calculation

- Calculation of bias resistor 1 (R1)

$$R1 = \frac{V(I_{I2}) - V(I_{I1})}{I_{I2} - I_{I1}}$$

- Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I_{I4}) - V(I_{I3})}{R1 \cdot (I_{I4} - I_{I3})} - 1$$

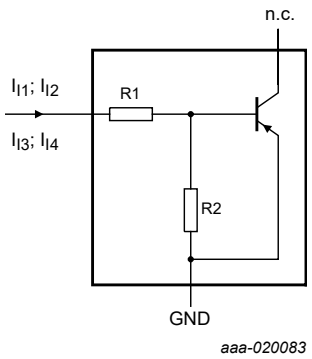


Fig. 35. PNP transistor: Resistor test circuit

Resistor test conditions

Table 9. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I_{I1}	I_{I2}	I_{I3}	I_{I4}
PDTA143XQC-Q	4.7	10	-350 µA	-450 µA	350 µA	450 µA
PDTA123JQC-Q	2.2	47	-90 µA	-140 µA	55 µA	105 µA
PDTA143ZQC-Q	4.7	47	-90 µA	-140 µA	55 µA	105 µA
PDTA114YQC-Q	10	47	-90 µA	-140 µA	55 µA	105 µA
PDTA124XQC-Q	22	47	-55 µA	-105 µA	55 µA	105 µA

12. Package outline

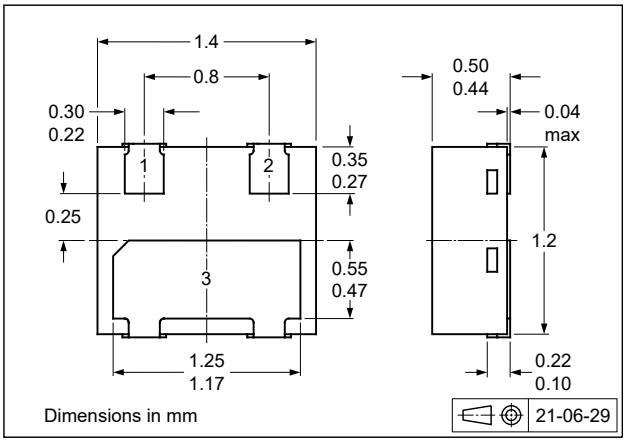


Fig. 36. Package outline DFN1412D-3 (SOT8009)

13. Soldering

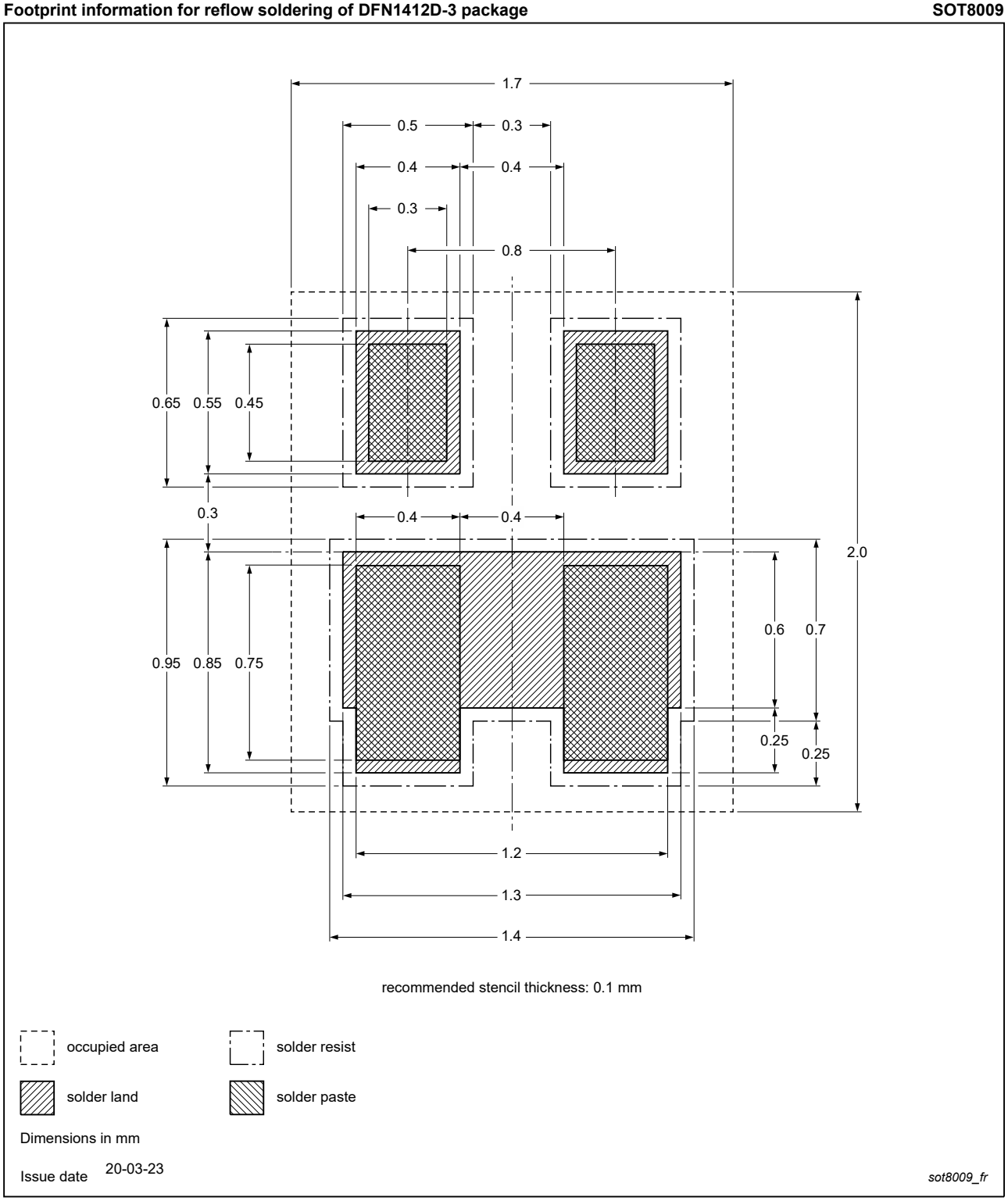


Fig. 37. Reflow soldering footprint DFN1412D-3 (SOT8009)

14. Revision history

Table 10. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PDTA143X_TO_124XQC-Q_SER v.1	20210930	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section "Definitions".
[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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Date of release: 30 September 2021